NSN 5961-01-395-4984

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Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-395-4984 **Inclosure Material:** Metal **Overall Length:** Between 4.07 millimeters and 4.57 millimeters **Terminal Length:** Between 12.70 millimeters and 19.05 millimeters **Overall Diameter:** Between 8.64 millimeters and 9.39 millimeters **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-205af **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 1.00 amperes drain current **Power Rating Per Characteristic:** 8.33 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: